Declaration For U.S. Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled (Insert Title)

BIAS SPUTTERING FILM FORMING PROCESS AND BIAS SPUTTERING FILM FORMING APPARATUS

the speci	fication of v	which is attached l	ereto unless the follo	wing box is check	ed:				
	was filed	on				As PCT International Application			
	Number		and w	vas amended on					
And/or	was filed	on			As United State	es Application	1		
	Number		and was amended on						
I hereby any amer	state that I ndment refe	have reviewed and red to above.	d understand the cont	ents of the above-	identified specifi	cation, includ	ing the cla	aim(s), as amended by	
I acknow	ledge the d	uty to disclose info	ormation which is mat	terial to patentabil	ty as defined in 3	37 C.F.R. §1.5	56.		
I hereby certificate and have date befo	claim fore e, or §365(a also identi ore that of th	ign priority beneal a) of any PCT Inte fied below any fo the application(s) for	fits under 35 U.S.C. crnational application reign application for which priority is class	§119(a)-(d) or § which designated patent or inventor imed:	365(b) of any fo at least one cour 's certificate or I	oreign applicantry other than PCT Internation		or patent or inventor' ed States, listed below ication having a filing	
	268	8019/2002	Japan	13 S 4	ptember 2002		Priority C		
(List pr	ior (Num		(Country)		th/Year Filed)		M les	□ 140	
foreign applicat	tions) —						X Yes	□No	
арриса	(Num	ber)	(Country)	(Day/Mor	th/Year Filed)				
		(Application Number)		(Filing Date)		-0			
		(Application Number)		(Filing Date)					
		☐ See a	ttached list for addition	onal prior foreign	or provisional ap	plications.			
disclosed to disclos	in the prior	r application(s) (U	J.S.C. §120 of any Urica listed below and S. or PCT) in the mater all to patentability as of Tinternational filing	nner provided by the side of t	he first paragrap	5(c) of any Peach of the characteristics of t	CT Interr laims of t C. §112, I le between	national application(s) this application is not acknowledge the duty not the filing date of the	
List prior U	J.S.								
Applications of the CT Internations of the CT Internations lesignating the CT Internations of the CT Internations	tional	(Application Serial No.)	pplication Serial No.)		(S	(Status) (patented, pending,		g, abandoned)	
	the U.S.)	(Application Serial No.)		(Filing Date)	(S	Status) (patented, pending	led, pending, abandoned)		
I. ILIGHO	<i>y</i> , 105, 110,	nt the firm of Are Marmelstein, Reg. bert K. Carpenter, an A. Tollefson, R 46,195; Bala Sun No. 46,592.	ent Fox, Customer N No. 25,895; George E Reg. No. 34,794; Ru eg. No. 46,338, Lynn dararajan, Reg. No. 1	umber 004372 in E. Oram, Jr., Reg. I Istan Hill, Reg. No e D. Anderson, Re P50,900; Monica	cluding as princi No. 27,931; Rich o. 37,351; Hans . g. No. 46,412; D Kitts, Reg. No. 3	pal attorneys: ard J. Berman J. Crosby, Re D. Daniel Dzar 6,105; King I	Robert, Reg. No. 9. No. 44, a, II, Reg. 2. Wong,	B. Murray, Reg. No. 39,107; Murat Ozgu, 634, Lynn A. Bristol, No. 47,543, Jonathan Reg. No. 37,500; and	
Please dir	rect all comi	munications to the	following address:	ARENT FOX KI 1050 Connecticu Washington, D.C.	t Avenue, N.W.,	IN & KAHN, Suite 400	PLLC	1010	

The undersigned hereby authorizes the U.S. attorneys named herein to accept and follow instructions from the undersigned's assignee, if any, and/or, if the undersigned is not a resident of the United States, the undersigned's domestic attorney, patent attorney or patent agent, as to any action to be take in the Patent and Trademark Office regarding this application without direct communication between the U.S. attorneys and the undersigned. In the event of a change in the person(s) from whom instructions may be taken, the U.S. attorneys named herein will be so notified by the undersigned.

Telephone No. (202) 857-6000; Facsimile No. (202) 638-4810

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or f	irst inventor Myounggoo LEE		
Inventor's signature	Myounggoo Lee	August /	
Residence Shizu	ıoka, Japan	T.	ate
Citizenship Ko:	rean		
Post Office Address	C/o ULVAC, Inc. Institute for Semiconductor Technologies of 1220-1, Suyama 410-1231 Japan	a, Susono-shi, S	Shizuoka ————————————————————————————————————
Full name of second i	nventor Yoshihiro OKAMURA		
Inventor's signature	Yoshipisa Chamusa		4 . , 2003
Residence Shizu	uoka, Japan		ate
Citizenship Japan			
Post Office Address	C/o ULVAC, Inc. Institute for Semiconductor Technologies of 1220-1, Suyama 410-1231 Japan	a, Susono-shi, (Shizuoka
Full name of second i	nventor Kazuyuki TOMIZAWA		
Inventor's signature	Kazunski Tomizawa	August /	3 , 2003
Residence Shizi	uoka, Japan		Date
Citizenship Japan	nese		
Post Office Address	C/o ULVAC, Inc. Institute for Semiconductor Technologies of 1220-1, Suyama 410-1231 Japan	a, Susono-shi,	Shizuoka
Full name of second i	inventor Satoru TOYODA		
Inventor's signature	Satoru Toyoda	August /	9 , 2003
Residence Shize	uoka, Japn	L	Date
Citizenship Japan			
Post Office Address	C/o ULVAC, Inc. Institute for Semiconductor Technologies of 1220-1, Suyama 410-1231 Japan	a, Susono-shi,	Shizuoka ————
Full name of second	inventor Narishi GONOHE		
Inventor's signature	Naryho Genoke	August, /	
Residence Shize	uoka, Japan	Γ	Date
Citizenship Japan	nese		
Post Office Address	C/o ULVAC, Inc. Institute for Semiconductor Technologies of 1220-1, Suyama 410-1231 Japan	a, Susono-shi,	Shizuoka